



# Surface and Volume defects

**Thapar Institute of Engineering & Technology**  
**(Deemed to be University)**

Bhadson Road, Patiala, Punjab, Pin-147004

Contact No. : +91-175-2393201

Email : [info@thapar.edu](mailto:info@thapar.edu)



**THAPAR INSTITUTE**  
OF ENGINEERING & TECHNOLOGY  
(Deemed to be University)



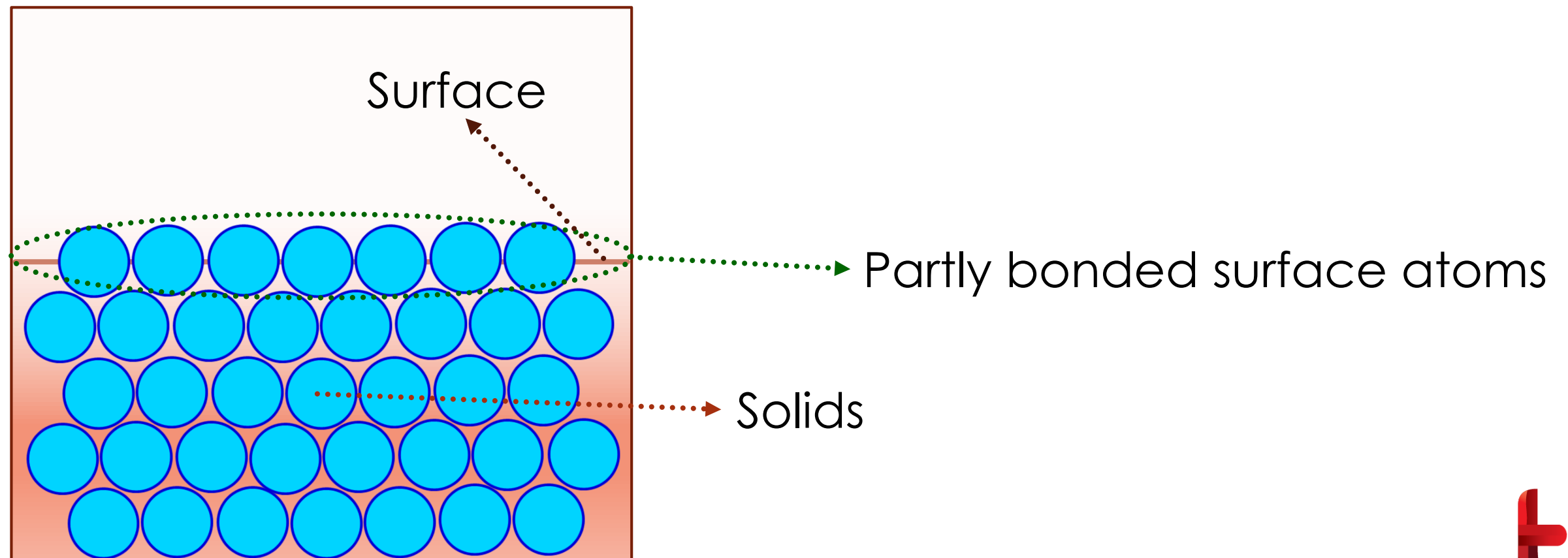
Area of distortion lie on surface which have negligible thickness compared to other two dimensions of the surface.

These defects are thermodynamically unstable and are present as metastable defects. Means under suitable condition these defects can be removed.

- Types of Surface Defects:
- Free surfaces
- Grain boundaries
- Twin boundaries
- Stacking faults

Surface defects normally divide regions of the materials with different crystal structures and/or crystallographic orientations

- Free surfaces are also known as external surfaces.
- Formed during the growth of crystal when stopped abruptly at the surface.
- Atoms in the free surfaces of solids (or even liquid) have no neighbours and have no cohesive-bonds on one side.

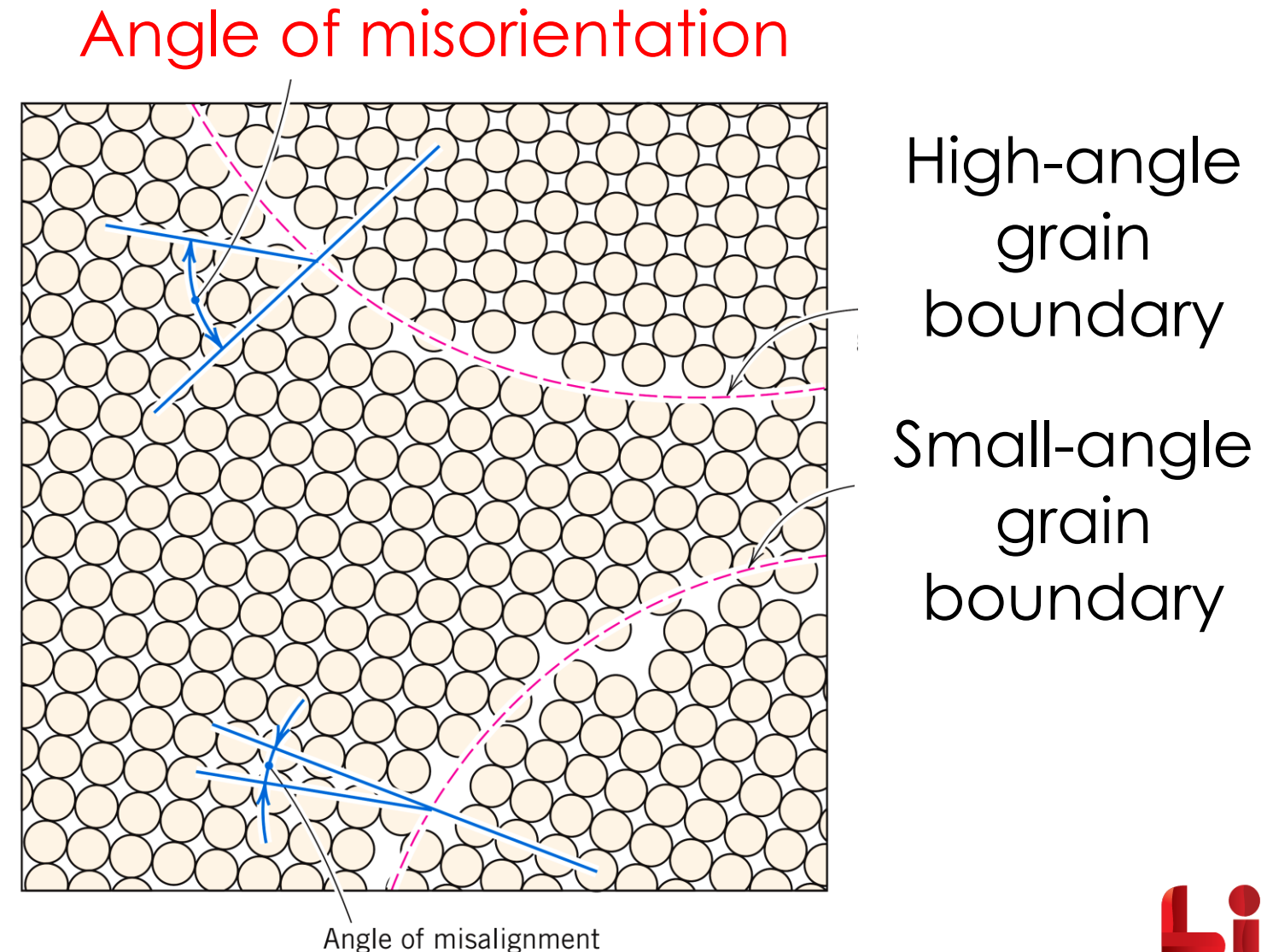


# Grain boundary

In a single phase polycrystalline material, a grain boundary is a two dimensional surface, which separate two regions with respect to there orientation of their crystal axes. Grain boundaries have disorder structure.

## Classification based on difference in orientation

1. Low angle boundaries: difference in orientation is between adjacent grain is less than  $\sim 10^\circ$ .
2. High angle boundaries: two adjacent grains have orientation difference more  $\sim 10^\circ$ , very large.



# Grain boundary

**Low angle grain boundaries** are boundaries between adjacent grains of same crystal structure, but with small difference in orientation. These boundaries might be considered to have an array of parallel dislocations (along the plane of the boundary)

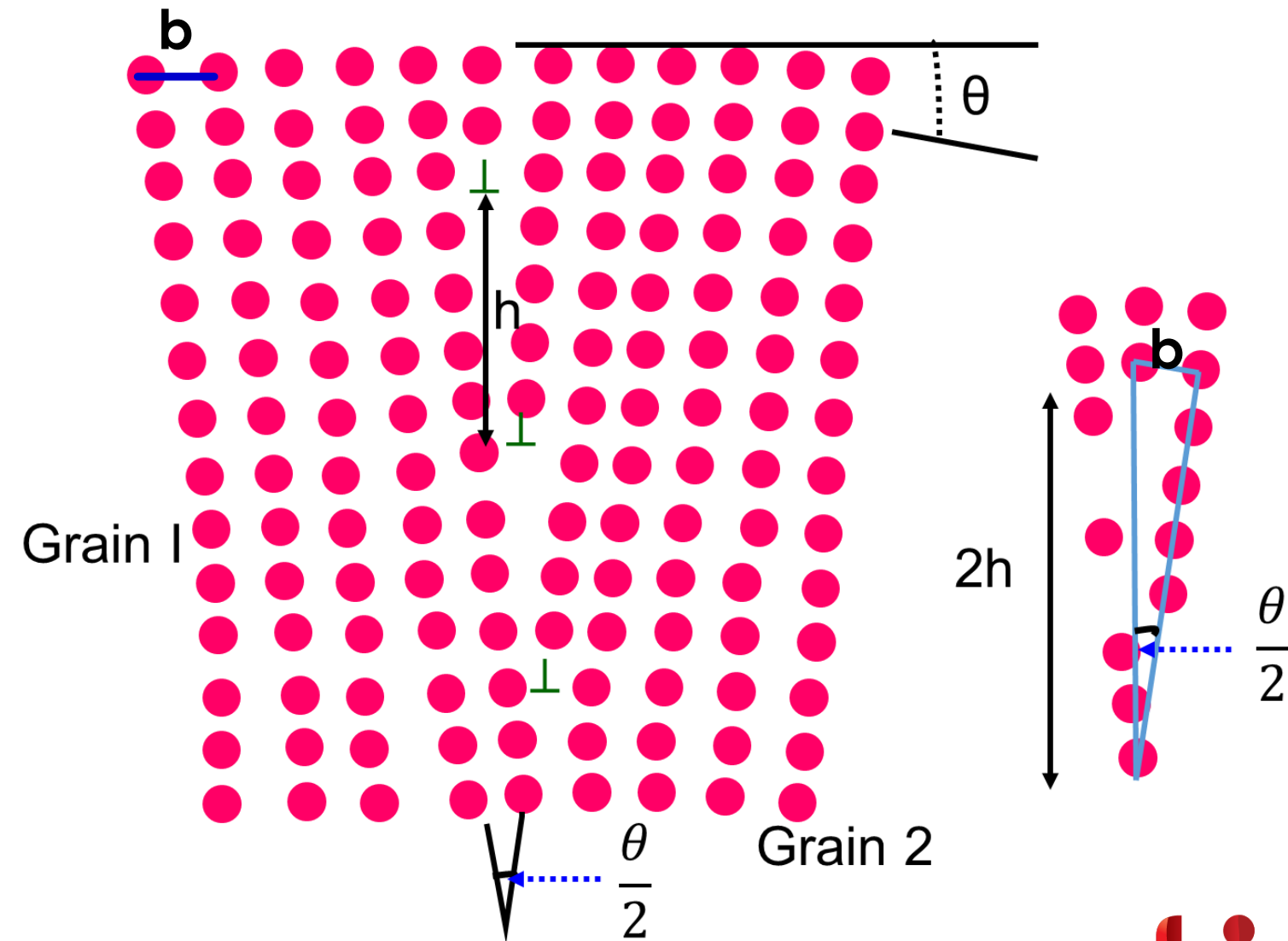
Here theta ( $\theta$ ) is the angle of misorientation or angle of tilt

$$\tan \frac{\theta}{2} = \frac{b}{2h}$$

Where  $b$  is the Burgers vector of dislocation in the boundary and  $h$  is the spacing between the two adjacent dislocation.

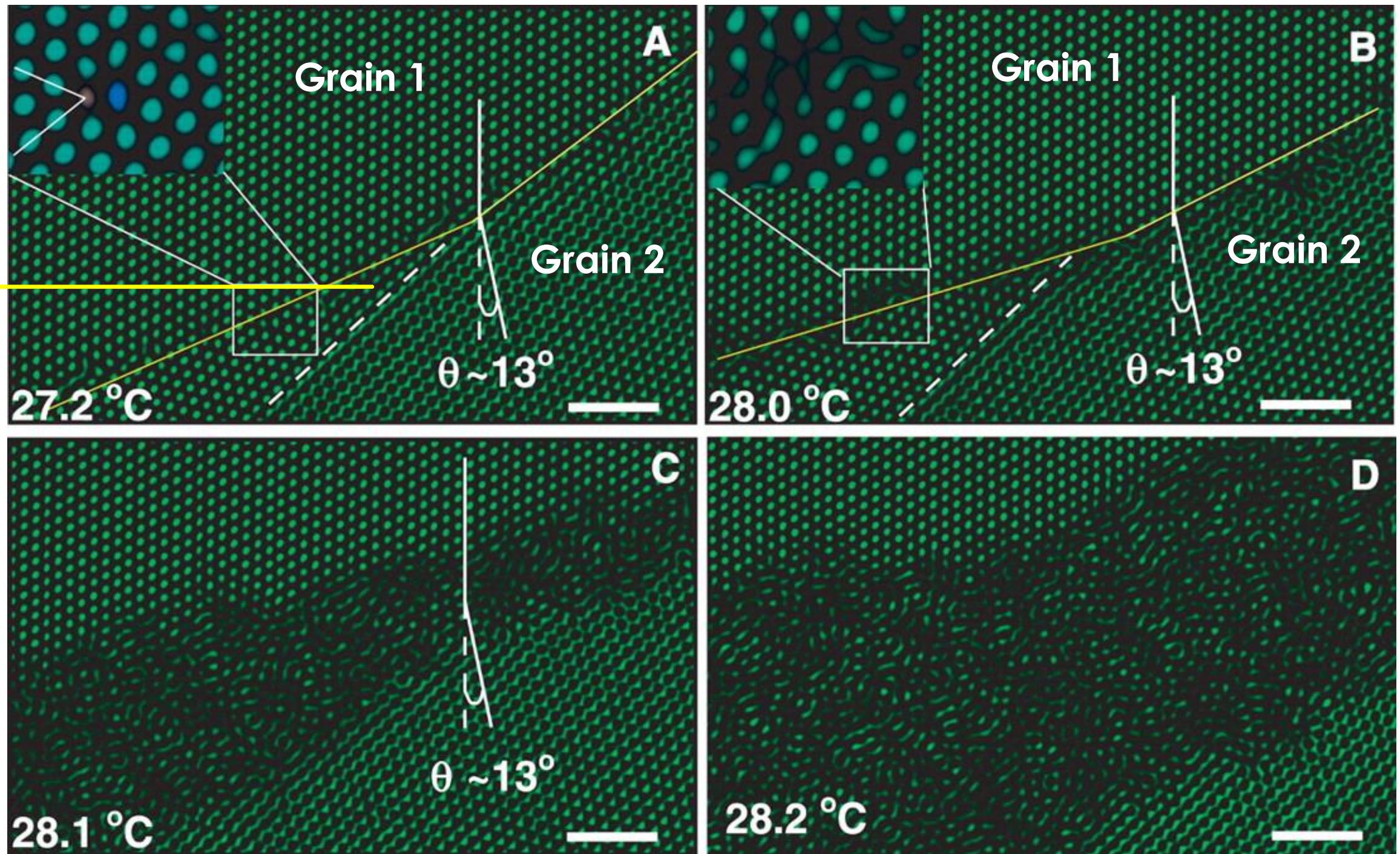
The angle of tilt is very small, it means  $\tan \frac{\theta}{2} = \frac{\theta}{2}$  and

$$\theta = \frac{b}{h}$$





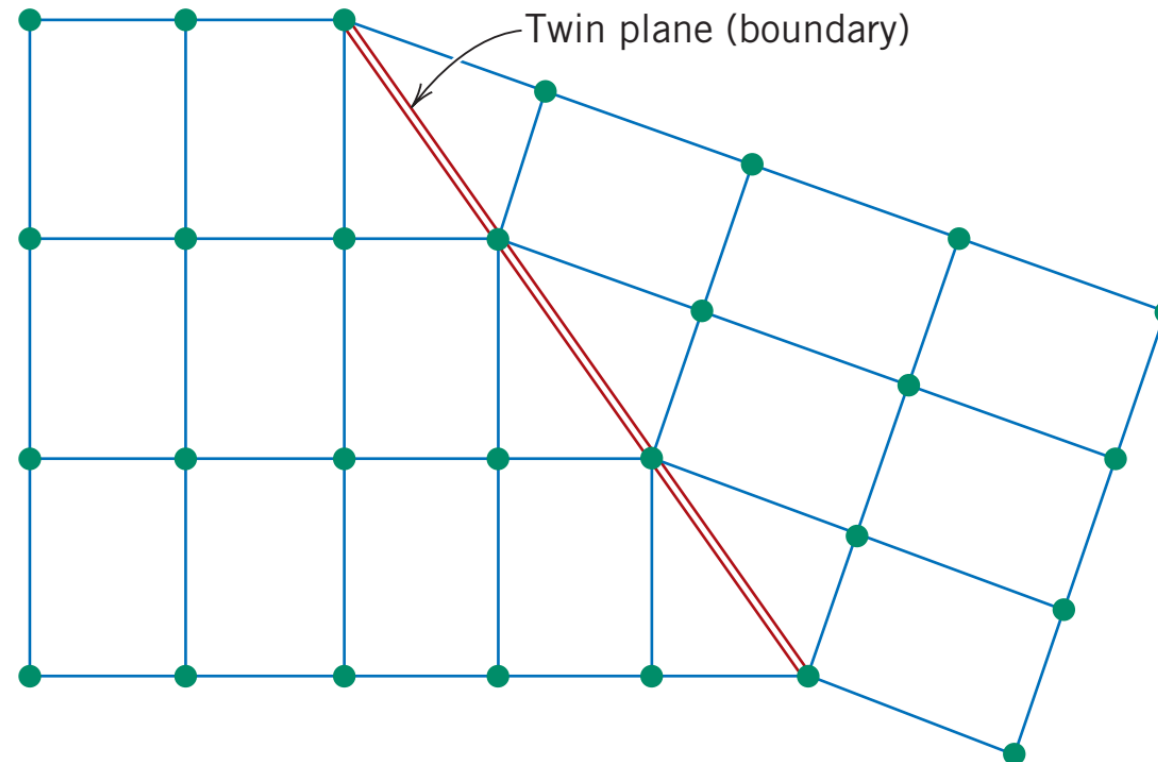
Grain  
boundary



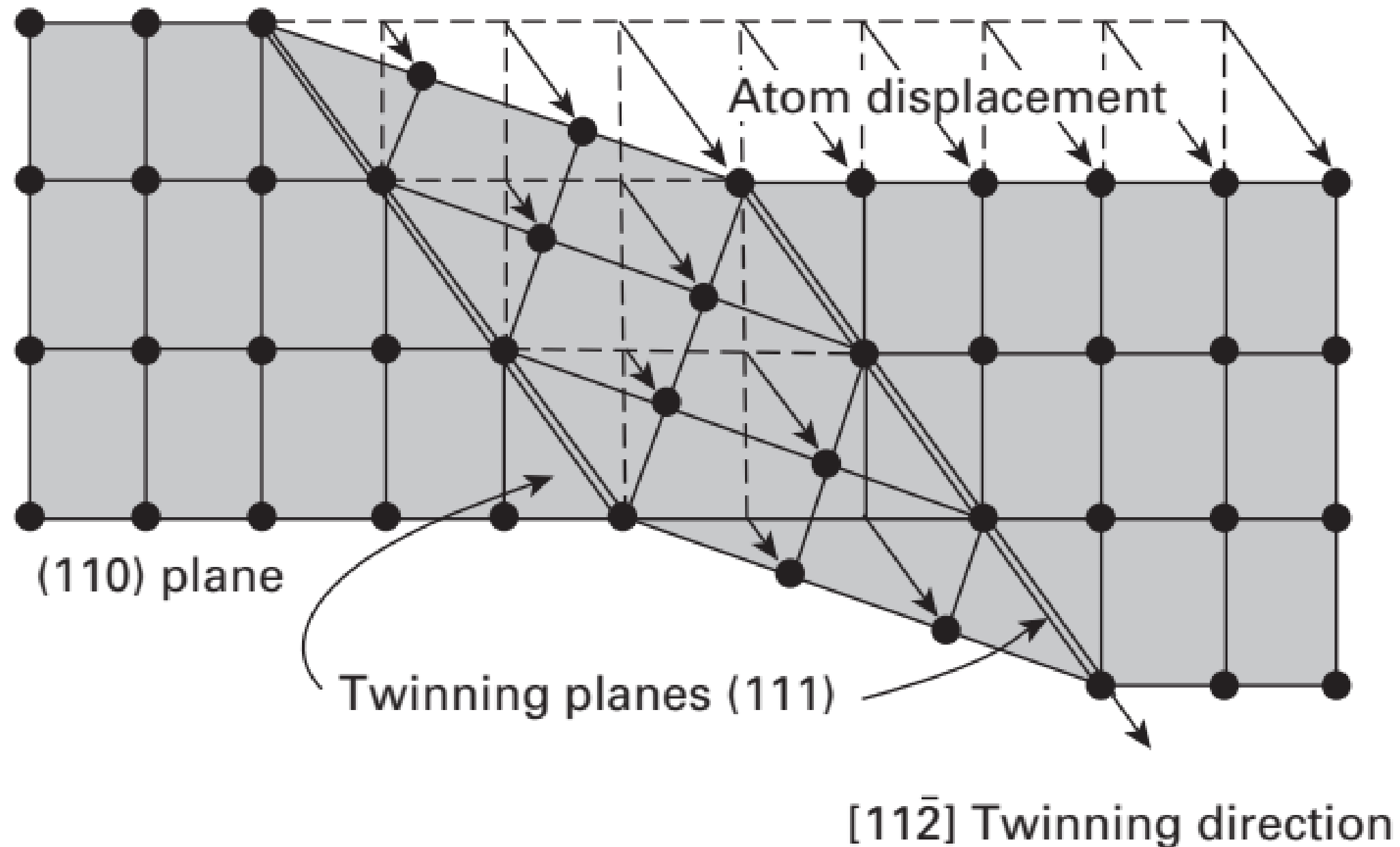


# Twin boundary

- These are the boundaries in the grains at which the atomic arrangement on one side of the boundary is mirror image of atoms on the other side.
- Twins occur in pairs. If change in orientation (of atoms) introduced by one boundary, then it is restored by the other boundary. The region between the pair of boundaries is called the twinned region.
- Twins are formed during deformation i.e. plastic deformation. They are called deformed twins.

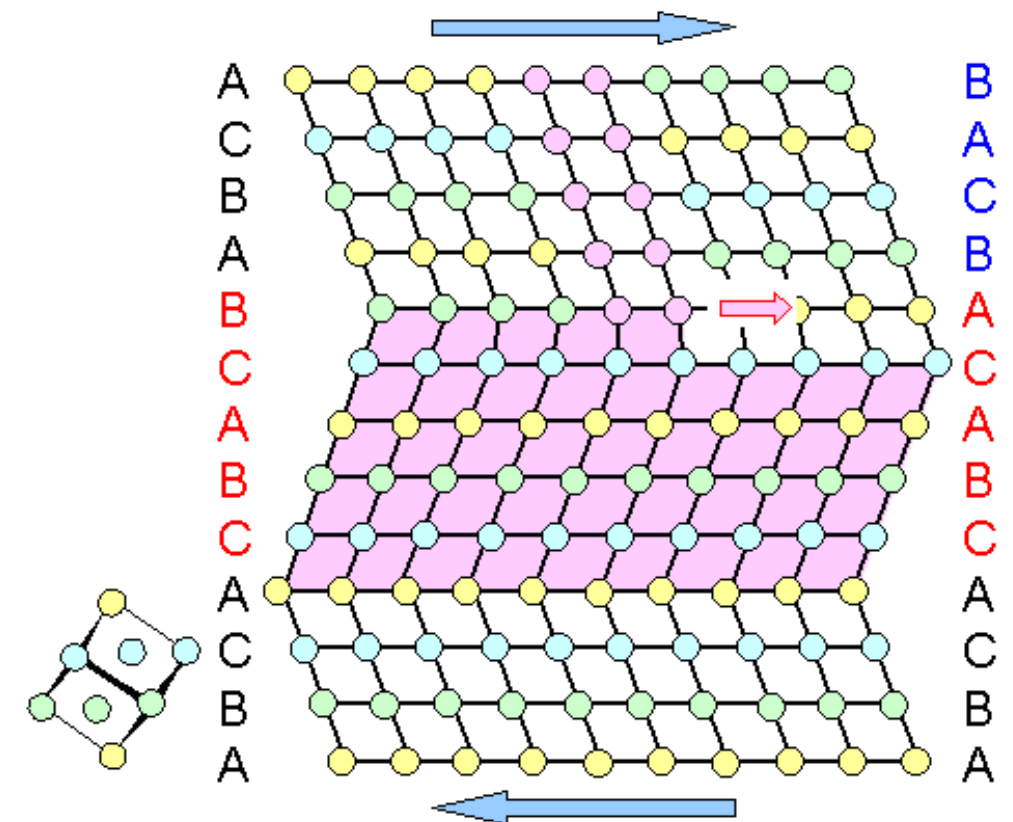
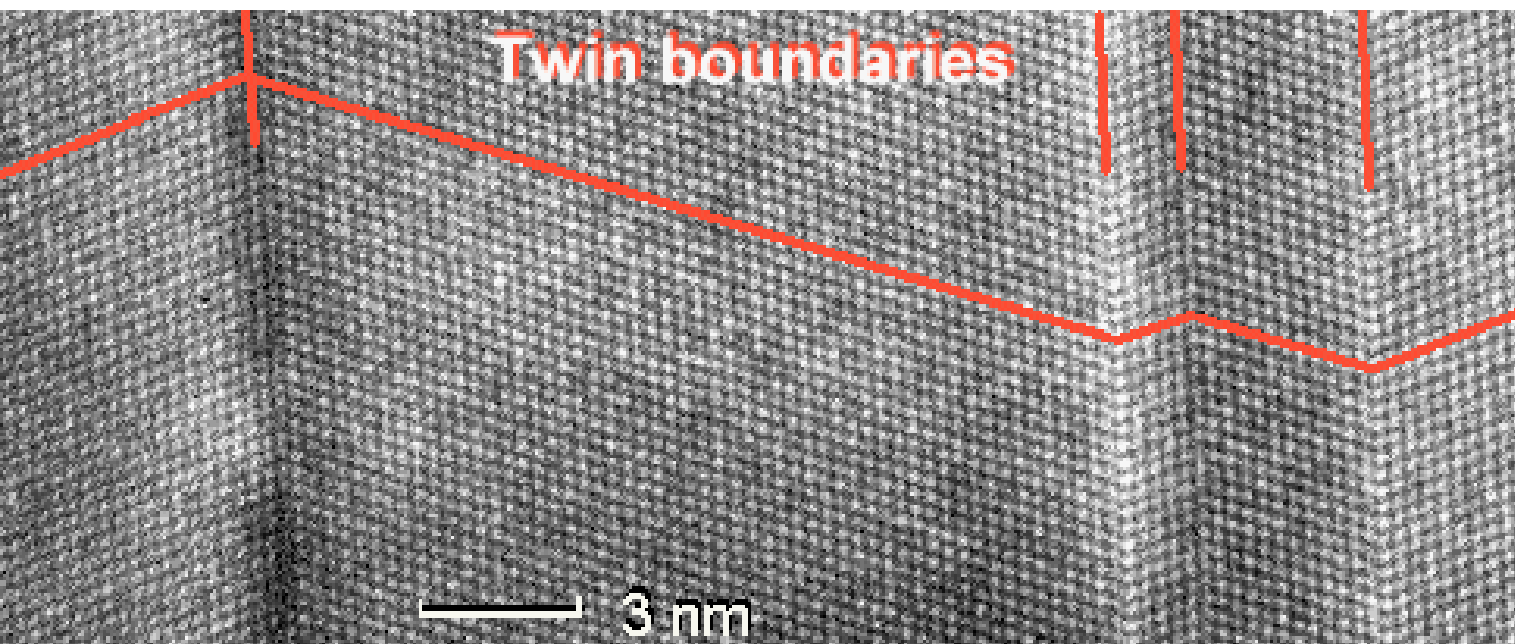
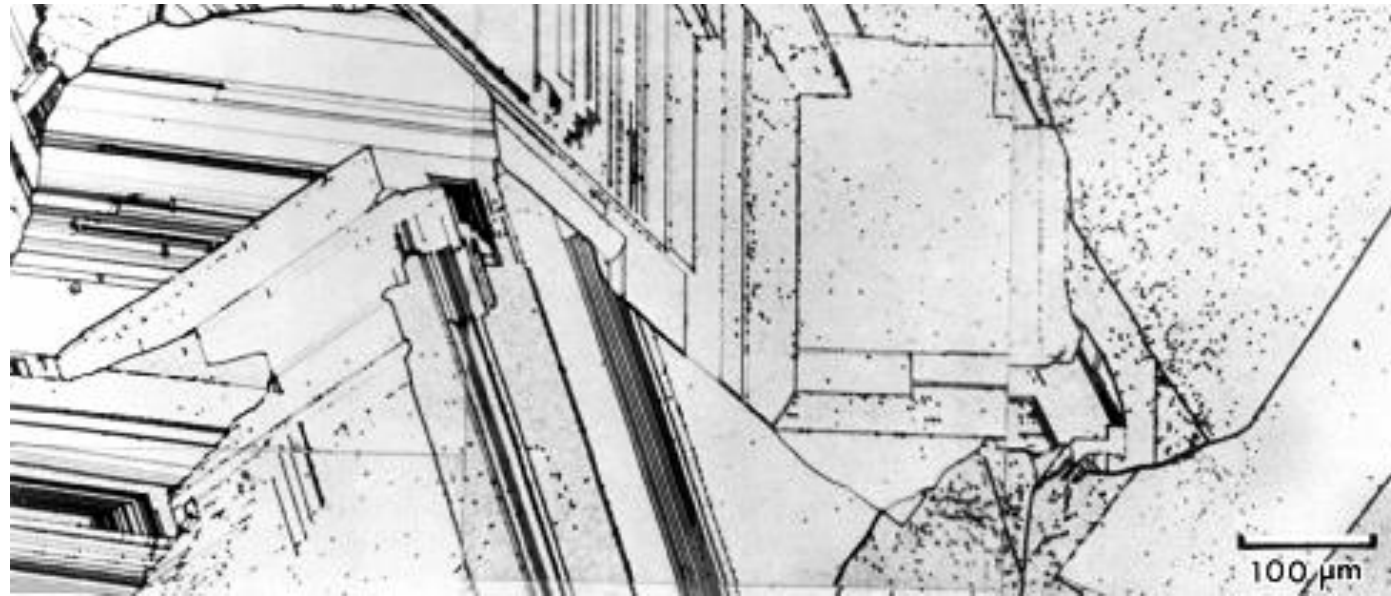


## Twining in FCC metals





# Twin boundary



- Formed by fault (mistake) in the stacking sequence of atomic planes in crystals.
- These defects can be produced by plastic deformation or by collapse of a large number of vacancies on one plane.
- Considering stacking arrangement in FCC

**A B C A B C A B C A B C A B C**

A is missing here

**A B C A B C B C A B C A B C**

Stacking Fault

- This thin region is a surface defect and is called stacking faults.



# Intrinsic Stacking Fault

11

This is formed by vacancy agglomeration and there is a missing plane with sequence, for example

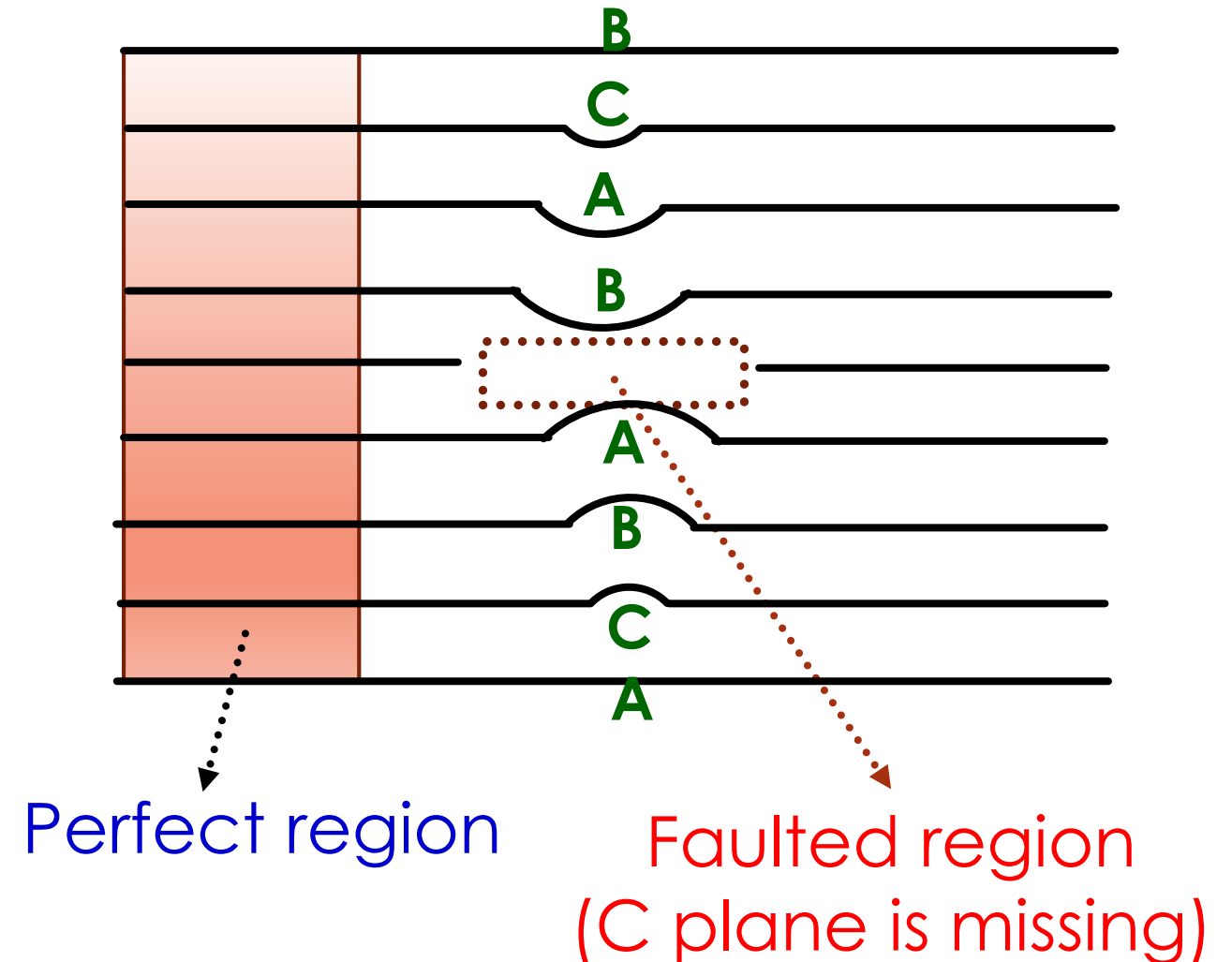
Missing Plane (C)



ABC ABC ABC ABC ABC

ABCABC AB ABC ABC

Here we see the four layers of an HCP stacking sequence in stacking fault in the FCC stacking sequence.



Intrinsic Stacking fault

# Extrinsic Stacking Fault

12

This is formed from interstitial agglomeration, where there is an extra plane with sequence, for example

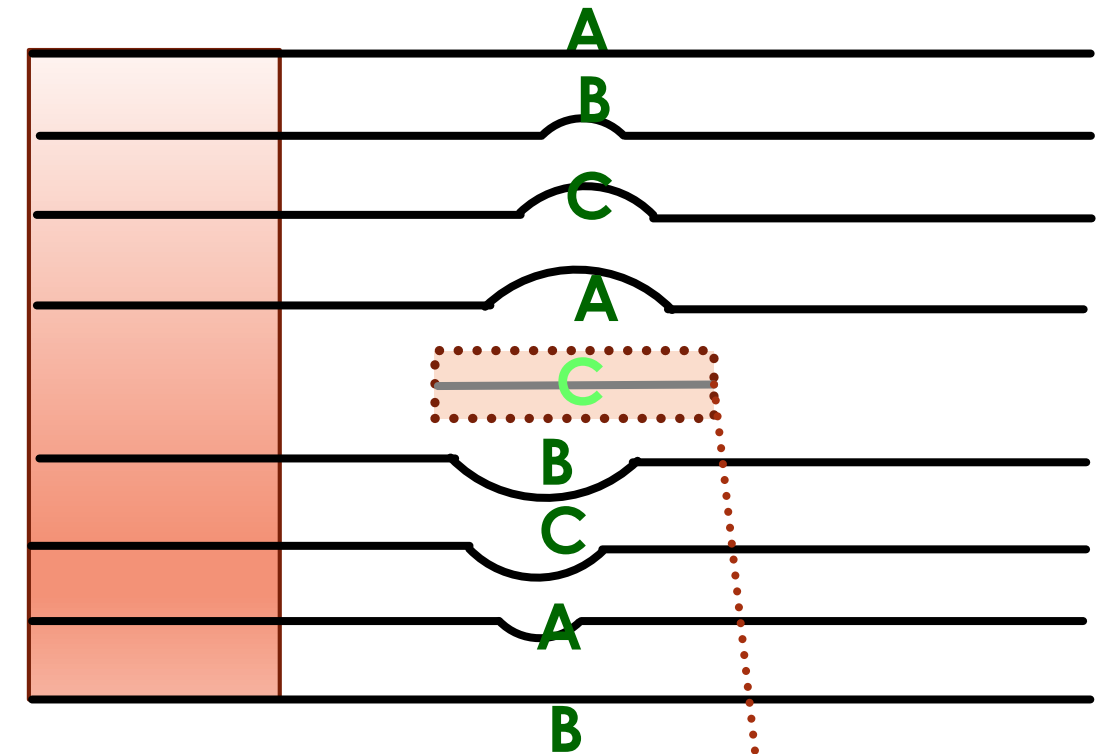
Extra plane added (C)



**ABC ABC ABC ABC ABC**

**ABC ABC ACBC ABC ABC**

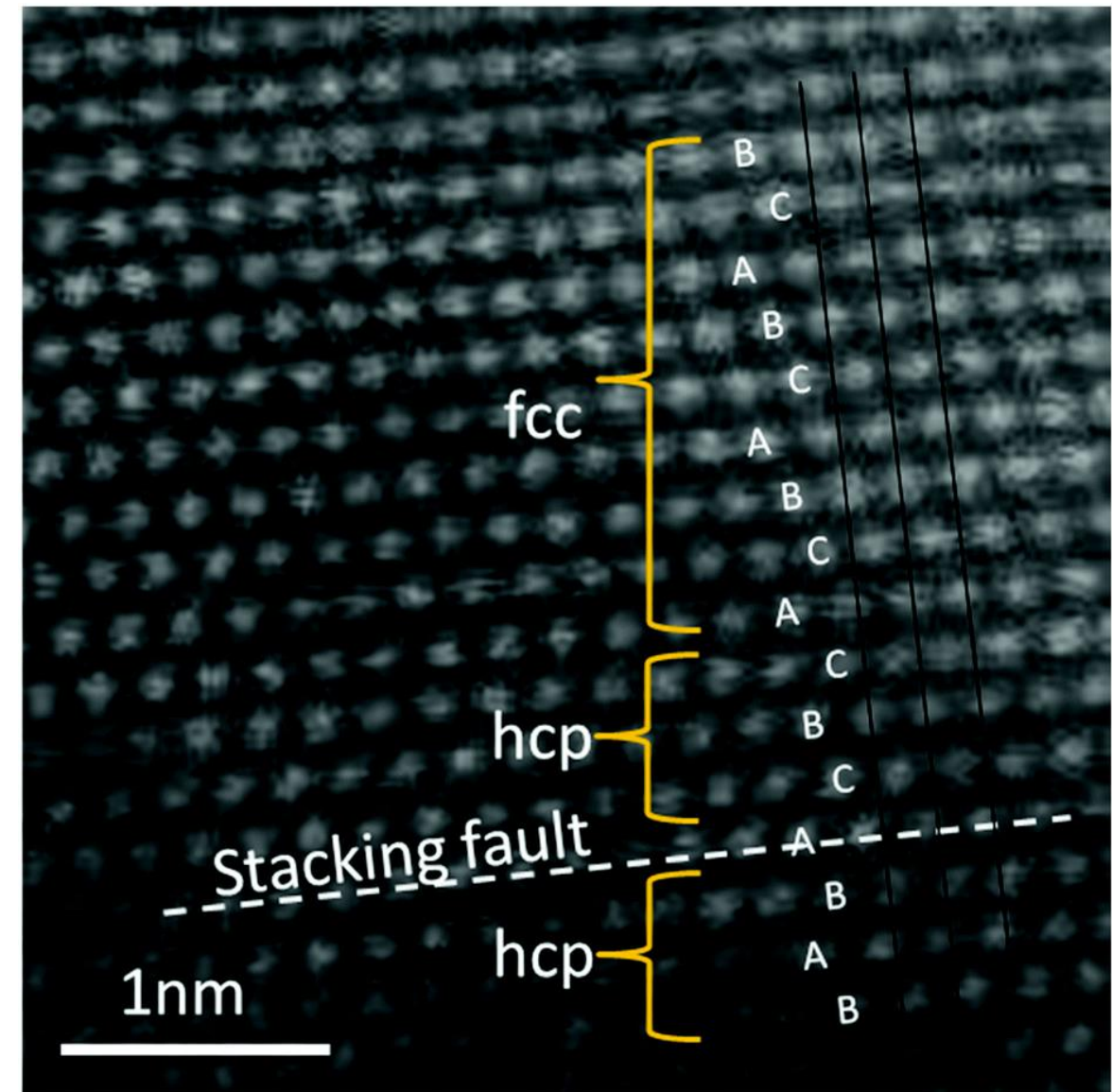
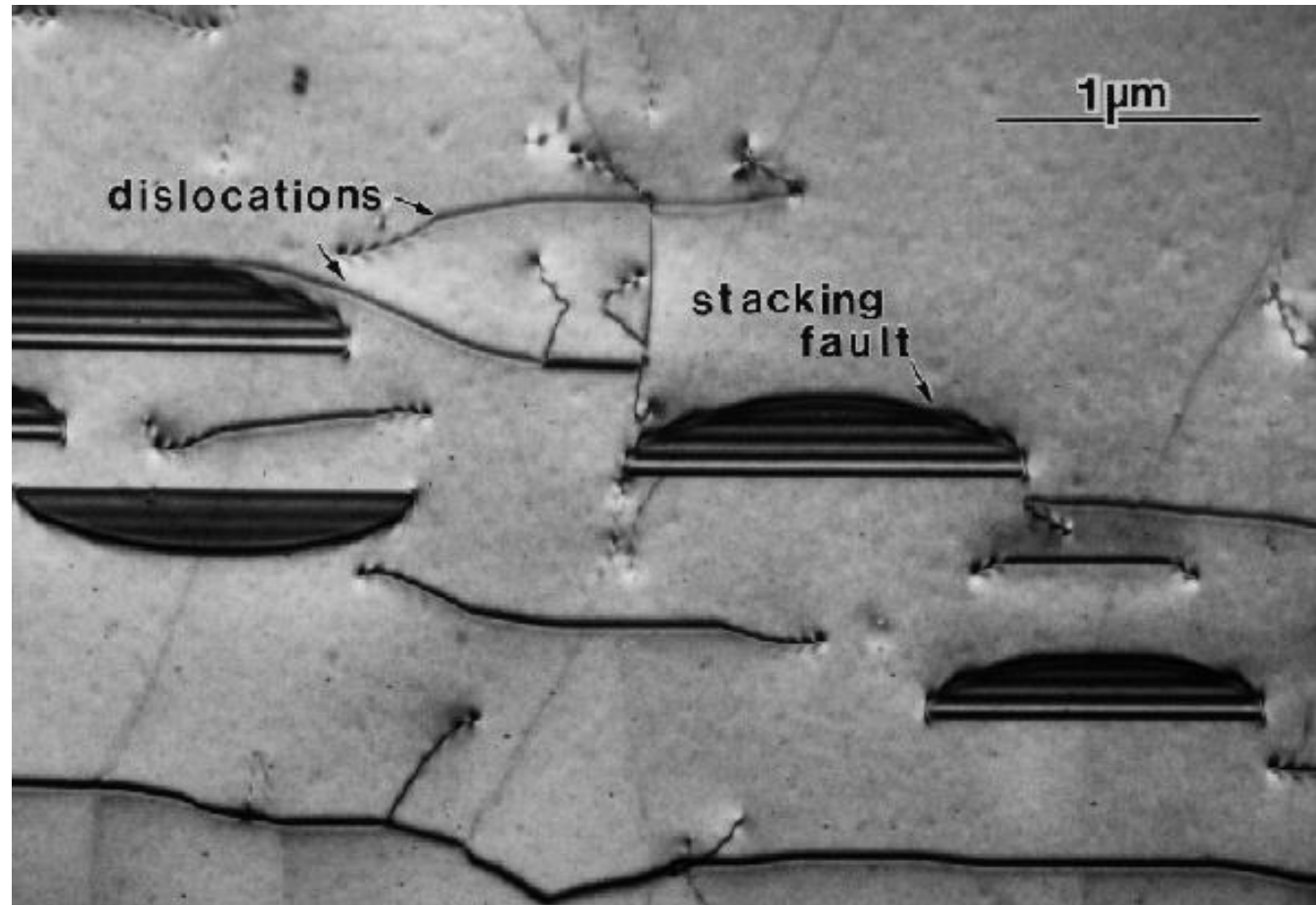
The three layers ACB constitute a twin (of BCA). Thus extrinsic stacking fault in FCC crystal is also called **twin stacking**.

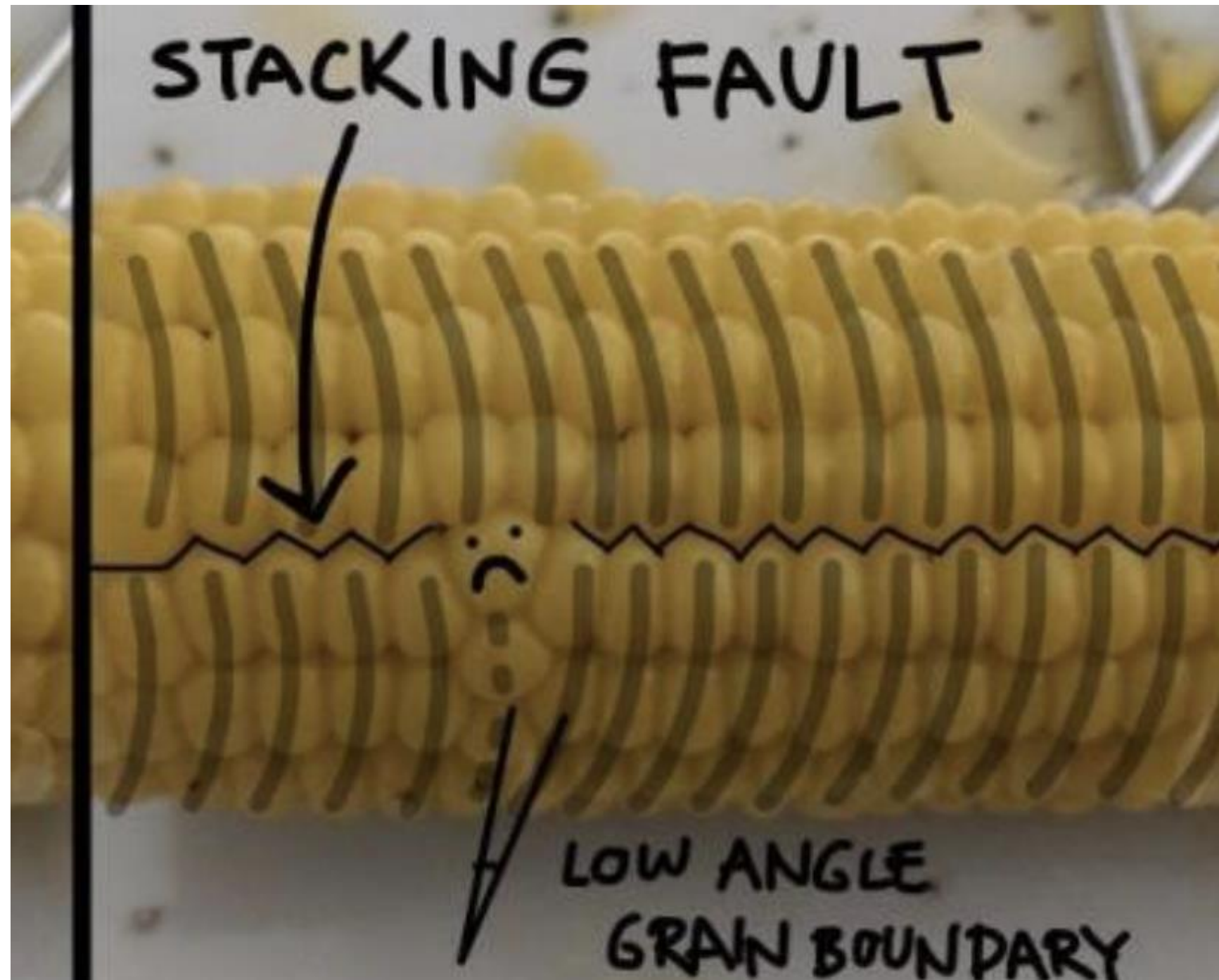


Two breaks introduced into stacking sequence (extra C plane is added)

Extrinsic Stacking fault









# Three Dimensional Defects: Bulk or Volume defects

15

These defects form during manufacturing processes for various reasons and are harmful to the materials

## Common 3-D defects

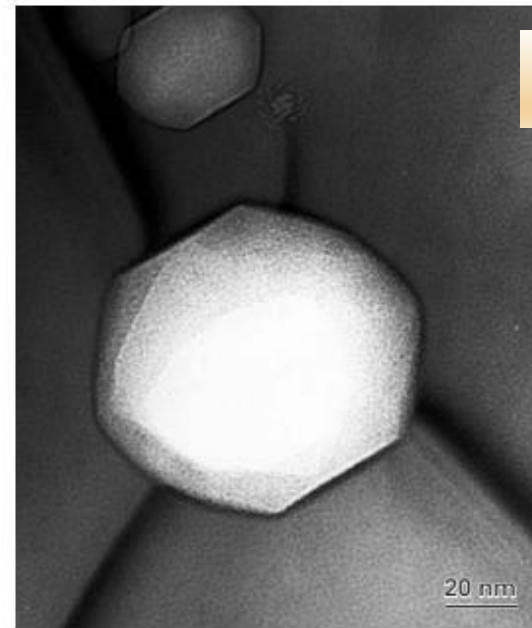
1. Precipitates

2. Voids

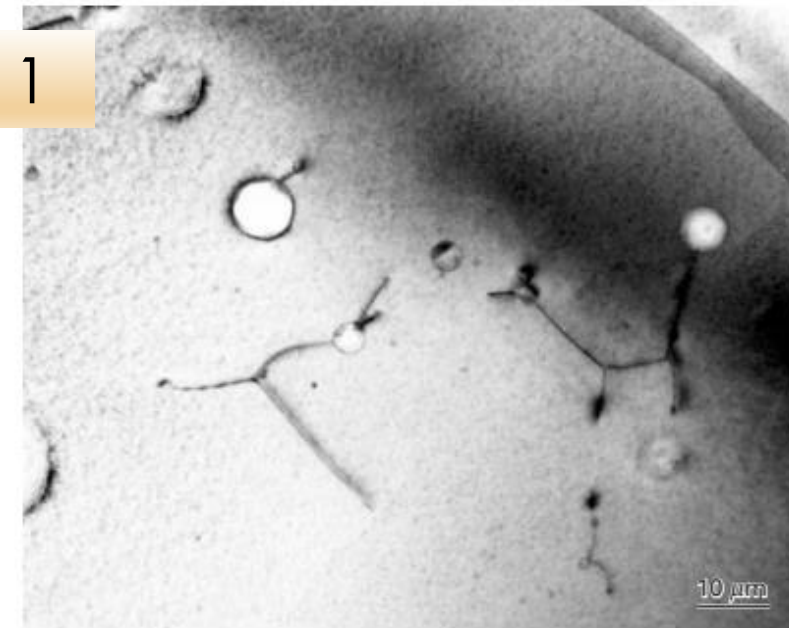
3. Pores (Porosity)

4. Inclusions

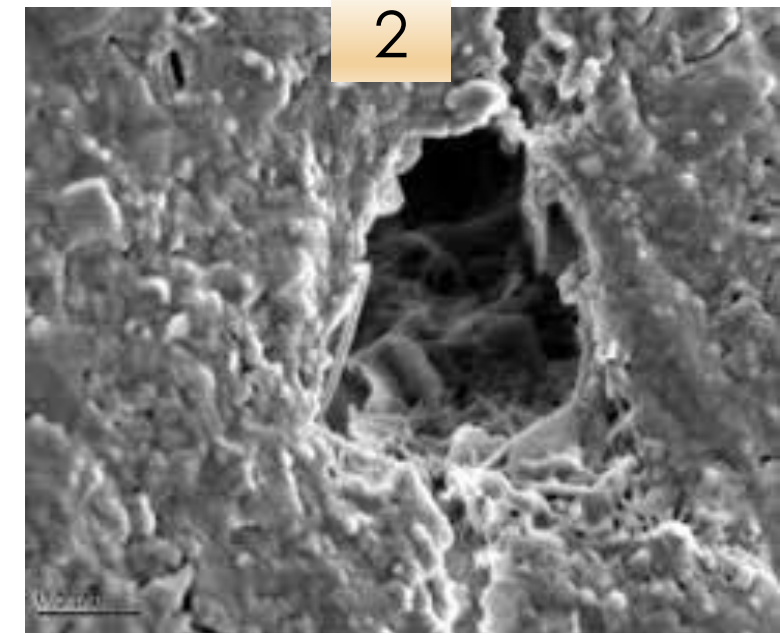
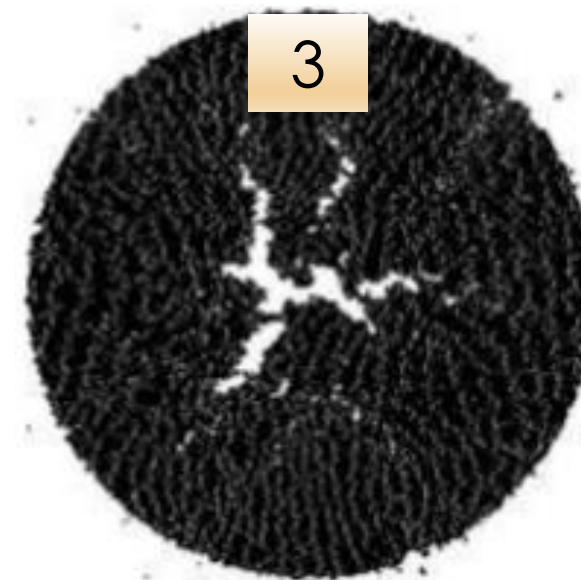
5. Cracks



(a)



(b)



1. All free surfaces are kind of a defect.
2. In low angle grain boundary, the misorientation angle is less than  $10^\circ$ .
3. In high angle grain boundary, the misorientation angle is greater than  $10^\circ$ .
4. Stacking fault formed by missing a plane.



1. The small angle boundary in FCC copper is due to extra (100) planes of atoms as edge dislocations. If the angle of disorientation is  $1^\circ$ , what is the distance between two neighboring edge dislocations? Given lattice parameter for Cu =  $3.62 \text{ \AA}$ .
2. Calculate the spacing between dislocation in a low angle tilt boundary in Iridium (FCC) when the angles of tilts are  $1^\circ$  and  $3^\circ$ . Lattice constant of Ir is  $3.84 \text{ \AA}$ .